

74VHC02 Quad 2-Input NOR Gate

General Description

The VHC02 is an advanced high-speed CMOS 2-Input NOR Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The internal circuit is composed of 3 stages, including buffer output, which provide high noise immunity and stable output. An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such

as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

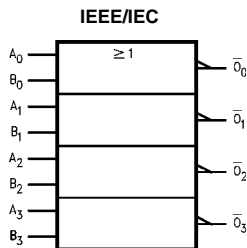
- High Speed: $t_{PD} = 3.6$ ns (typ) at $V_{CC} = 5$ V
- Low power dissipation: $I_{CC} = 2$ μ A (max) at $T_A = 25^\circ$ C
- High noise immunity: $V_{NIH} = V_{NIL} = 28\%$ V_{CC} (min)
- Power down protection is provided on all inputs
- Low noise: $V_{OLP} = 0.8$ V (max)
- Pin and function compatible with 74HC02

Ordering Code:

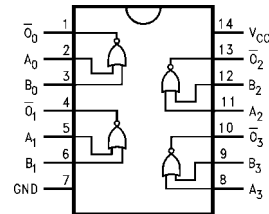
Order Number	Package Number	Package Description
74VHC02M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74VHC02SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC02MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC02N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
\bar{O}_n	Outputs

Truth Table

A	B	\bar{O}
L	L	H
L	H	L
H	L	L
H	H	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	-0.5V to +7.0V
DC Input Voltage (V_{IN})	-0.5V to +7.0V
DC Output Voltage (V_{OUT})	-0.5V to $V_{CC} + 0.5V$
Input Diode Current (I_{IK})	-20 mA
Output Diode Current (I_{OK})	± 20 mA
DC Output Current (I_{OUT})	± 25 mA
DC V_{CC}/GND Current (I_{CC})	± 50 mA
Storage Temperature (T_{STG})	-65°C to +150°C
Lead Temperature (T_L) (Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	-40°C to +85°C
Input Rise and Fall Time (t_r, t_f)	
$V_{CC} = 3.3V \pm 0.3V$	0 ~ 100 ns/V
$V_{CC} = 5.0V \pm 0.5V$	0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25^\circ\text{C}$			$T_A = -40^\circ\text{C to } +85^\circ\text{C}$		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level	2.0	1.50			1.50		V		
	Input Voltage	3.0 – 5.5	0.7 V_{CC}			0.7 V_{CC}				
V_{IL}	LOW Level	2.0	0.50			0.50		V		
	Input Voltage	3.0 – 5.5	0.3 V_{CC}			0.3 V_{CC}				
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0	1.9		V	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -50 \mu\text{A}$	
		3.0	2.9	3.0	2.9					
		4.5	4.4	4.5	4.4					
		3.0	2.58		2.48					
V_{OL}	LOW Level Output Voltage	2.0	0.0			0.1		V	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 50 \mu\text{A}$
		3.0	0.0			0.1				
		4.5	0.0			0.1				
		3.0	0.36			0.44				
I_{IN}	Input Leakage Current	0 – 5.5				± 0.1		μA	$V_{IN} = 5.5V$ or GND	
	I_{CC}	Quiescent Supply Current	5.5	2.0			20.0			

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = 25^\circ\text{C}$		Units	Conditions
			Typ	Limits		
V_{OLP} (Note 3)	Quiet Output Maximum	5.0	0.3	0.8	V	$C_L = 50 \text{ pF}$
	Dynamic V_{OL}					
V_{OLV} (Note 3)	Quiet Output Minimum	5.0	-0.3	-0.8	V	$C_L = 50 \text{ pF}$
	Dynamic V_{OL}					
V_{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0	3.5		V	$C_L = 50 \text{ pF}$
V_{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0	1.5		V	$C_L = 50 \text{ pF}$

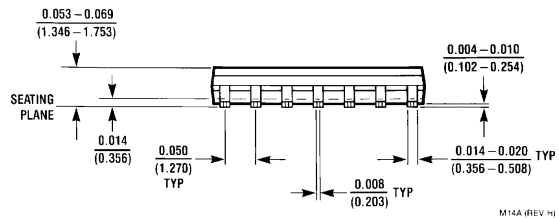
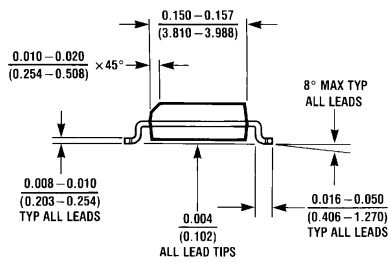
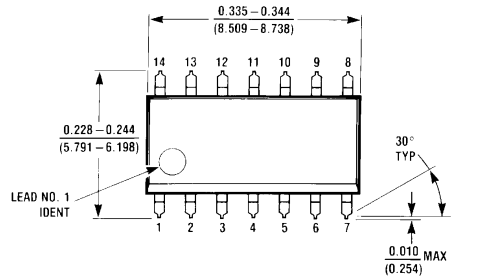
Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

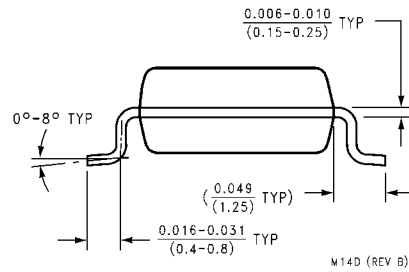
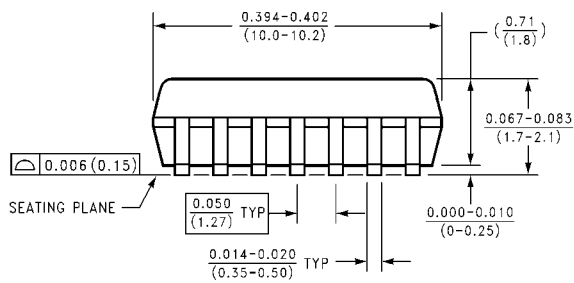
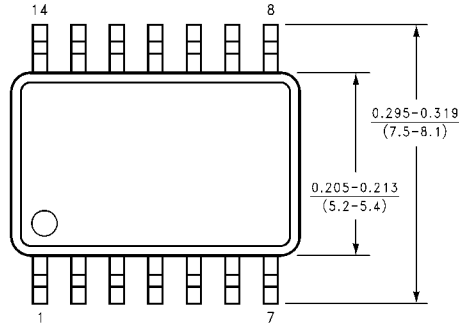
Symbol	Parameter	V _{CC} (V)	T _A = 25°C			T _A = -40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
t _{PHL}	Propagation Delay	3.3 ± 0.3		5.6	7.9	1.0	9.5	ns	C _L = 15 pF
t _{PLH}				8.1	11.4	1.0	13.0		C _L = 50 pF
		5.0 ± 0.5		3.6	5.5	1.0	6.5	ns	C _L = 15 pF
				5.1	7.5	1.0	8.5		C _L = 50 pF
C _{IN}	Input Capacitance			4	10		10	pF	V _{CC} = Open
C _{PD}	Power Dissipation Capacitance			15				pF	(Note 4)

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC (opr.)} = C_{PD} * V_{CC} * f_{IN} + I_{CC}/4 (per gate).

Physical Dimensions inches (millimeters) unless otherwise noted

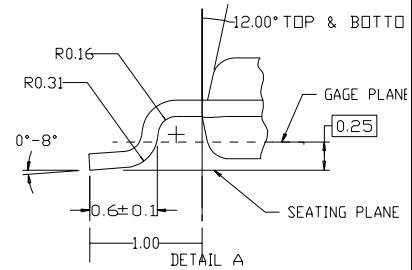
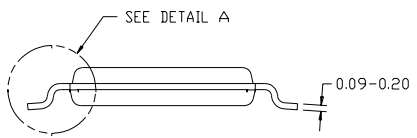
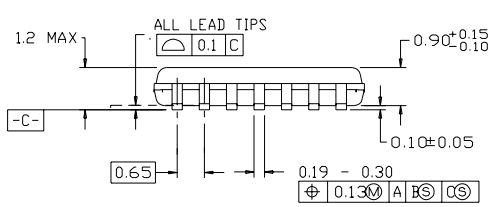
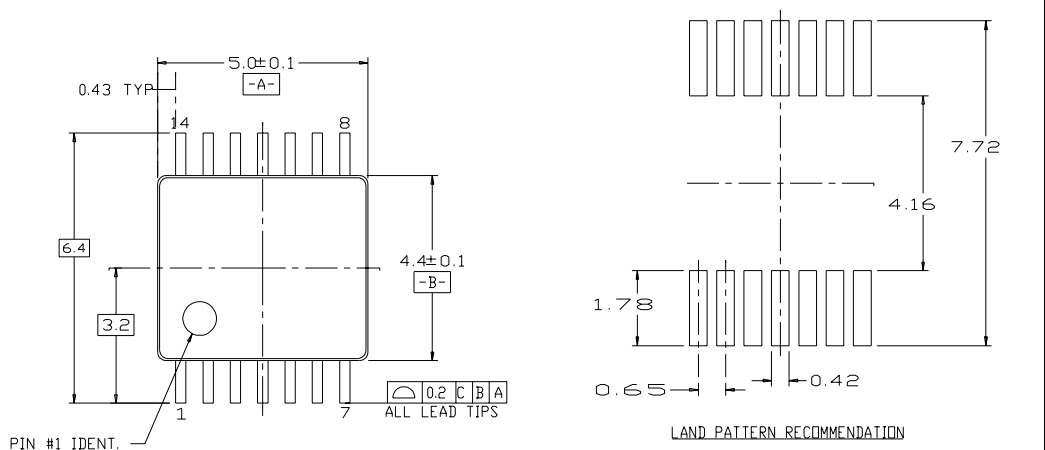


**14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A**



**14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D**

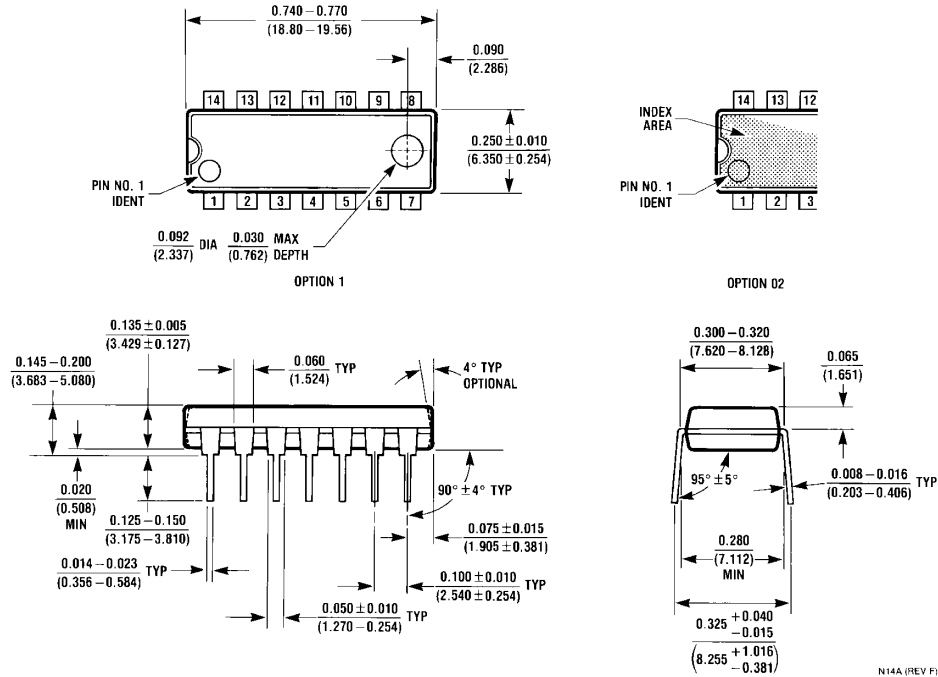
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



- NOTES:
- A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93
 - B. DIMENSIONS ARE IN MILLIMETERS
 - C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com